NSN 5962-00-551-9475

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View Online at https://aerobasegroup.com/nsn/5962-00-551-9475

Body Length:

Between 1.208 inches and 1.232 inches

Body Width:

Between 0.495 inches and 0.505 inches

Body Height:

0.060 inches

Maximum Power Dissipation Rating:

1.25 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and high speed and monolithic and low power and negative outputs

Inclosure Material:

Ceramic and metal

Inclosure Configuration:

Dual-in-line

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

30.0 volts power source

Time Rating Per Chacteristic:

100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Precious Material And Location:

Terminal surface gold

Precious Material:

Gold

Test Data Document:

12464-b77t0197 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

